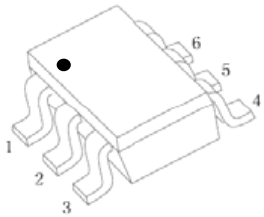
SOT-23-6L Plastic-Encapsulate MOSFETS

CJL8810A Dual N-Channel MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$TYP	I_D
20V	12.8mΩ@4.5V	7A
	13.0mΩ@3.8V	
	15.0mΩ@2.5V	
	21.5mΩ@1.8V	

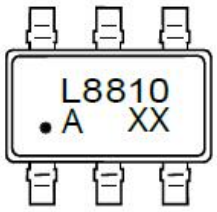
SOT-23-6L



DESCRIPTION

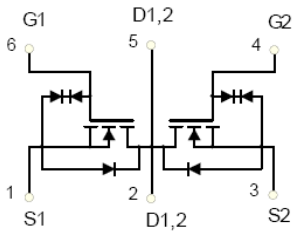
The CJL8810A uses advanced trench technology to provide excellent $R_{DS(ON)}$ and low gate charge. It is ESD protected. This device is suitable for use as a uni-directional or bi-directional load switch,facilitated by its common-drain configuration.

MARKING



L8810A=Device code
Solid point=Pin1 positioning point
XX=Date Code

Equivalent Circuit



MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current	I_D	7	A
Pulsed Drain Current	I_{DM}*	30	A
Power Dissipation	P_D ③	1.25	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$ ③	100	℃/W
Operation Junction and Storage Temperature Range	T_J,T_{stg}	-55~+150	℃
Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	T_L	260	℃

*Repetitive rating：Pluse width limited by junction temperature.

MOSFET ELECTRICAL CHARACTERISTICS

T_a=25℃ unless otherwise specified

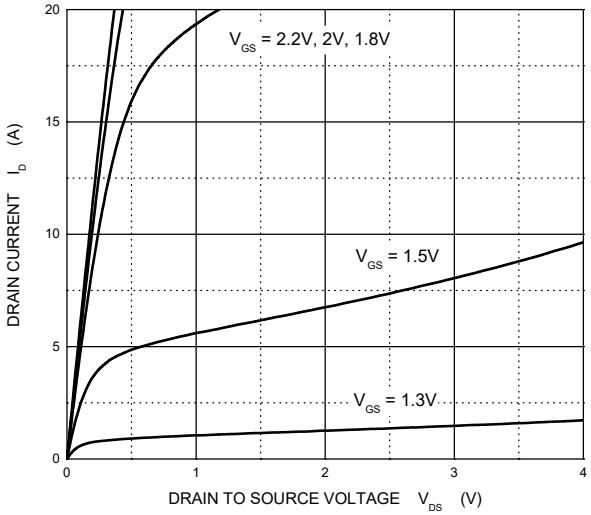
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =250μA	20			V
Zero gate voltage drain current	I_{DSS}	V_{DS} =16V,V_{GS} = 0V			1	μA
Gate-body leakage current	I_{GSS}	V_{GS} =±4.5V, V_{DS} = 0V			±1	μA
		V_{GS} =±10V, V_{DS} = 0V			±5	μA
Gate threshold voltage ①	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =250μA	0.4	0.8	1	V
Drain-source on-resistance ①	$R_{DS(on)}$	V_{GS} =10V, I_D =3A	10.0	12.0	15.5	mΩ
		V_{GS} =4.5V, I_D =3A	10.5	12.8	16.6	mΩ
		V_{GS} =3.8V, I_D =3A	10.8	13.0	17.0	mΩ
		V_{GS} =2.5V, I_D =3A	12.0	15.0	19.5	mΩ
		V_{GS} =1.8V, I_D =3A	16.0	21.5	35.0	mΩ
Forward tranconductance ①	g_{FS}	V_{DS} =5V, I_D =7A	9	10.5		S
Diode forward voltage ①	V_{SD}	I_S=1A, V_{GS} = 0V			1	V
DYNAMIC PARAMETERS ②						
Input Capacitance	C_{iss}	V_{DS} =10V,V_{GS} =0V,f =1MHz		785		pF
Output Capacitance	C_{oss}			137		pF
Reverse Transfer Capacitance	C_{rss}			100		pF
Total gate charge	Q_g	V_{DS} =10V,V_{GS} =4.5V,I_D =7A		7.7		nC
Gate-source charge	Q_{gs}			1.2		nC
Gate-drain charge	Q_{gd}			2.4		nC
SWITCHING PARAMETERS ②						
Turn-on delay time	$t_{d(on)}$	V_{GS}=5V,V_{DD}=10V, R_L=1.35Ω,R_{GEN}=3Ω		8.8		ns
Turn-on rise time	t_r			2.2		ns
Turn-off delay time	$t_{d(off)}$			65		ns
Turn-off fall time	t_f			26		ns

Notes :

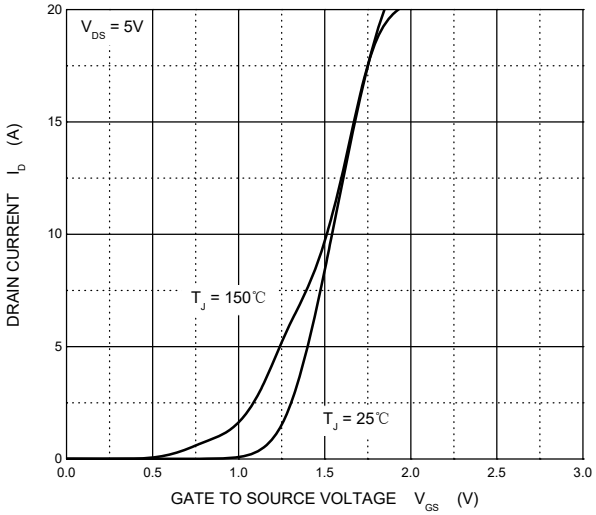
1. Pulse Test : Pulse width≤300μs, duty cycle≤0.5%.
2. Guaranteed by design, not subject to production testing.
3. The value of P_D&$R_{\theta JA}$ is measured with the device one sided actived, mounted on 1 in^2 FR-4 board with 2oz. Copper, single sided, in a still air environment with Ta=25℃.

Typical Characteristics

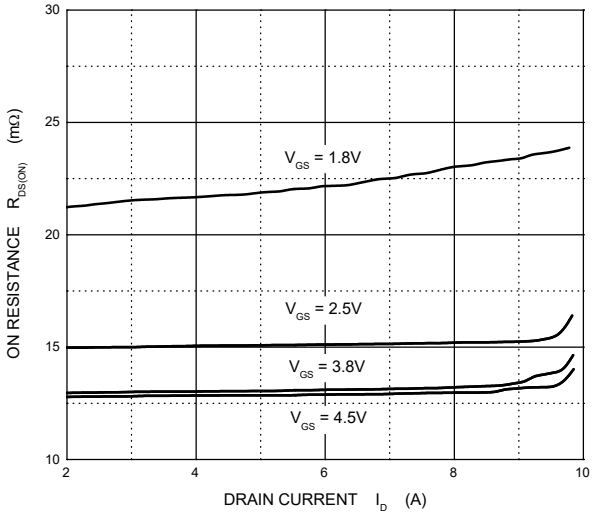
Output Characteristics



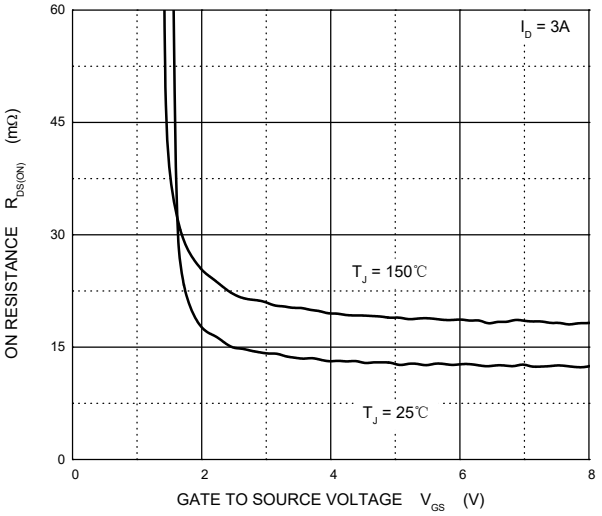
Transfer Characteristics



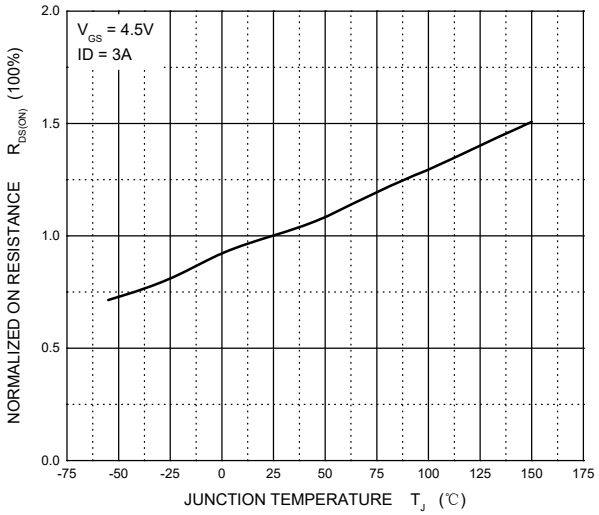
On Resistance vs. Drain Current



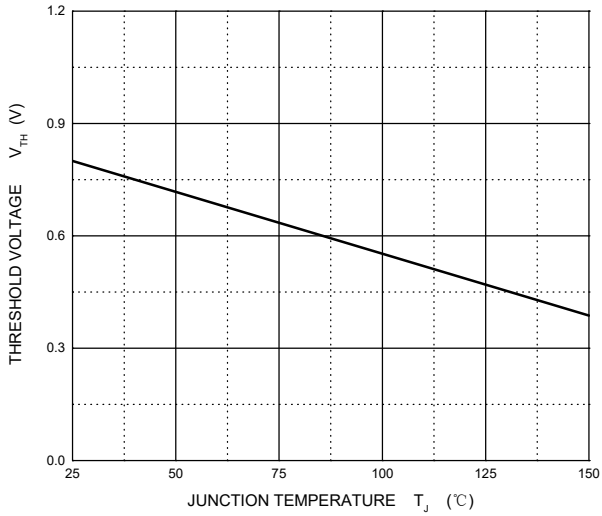
On Resistance vs. Gate-Source Bias



On Resistance vs. Junction Temperature

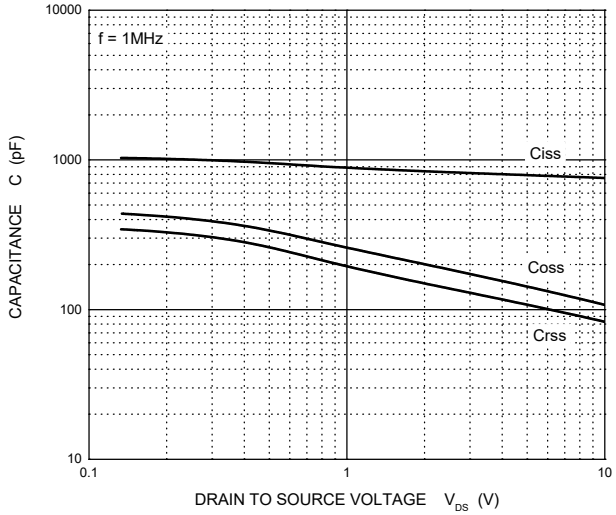


Gate-Source Threshold Voltage

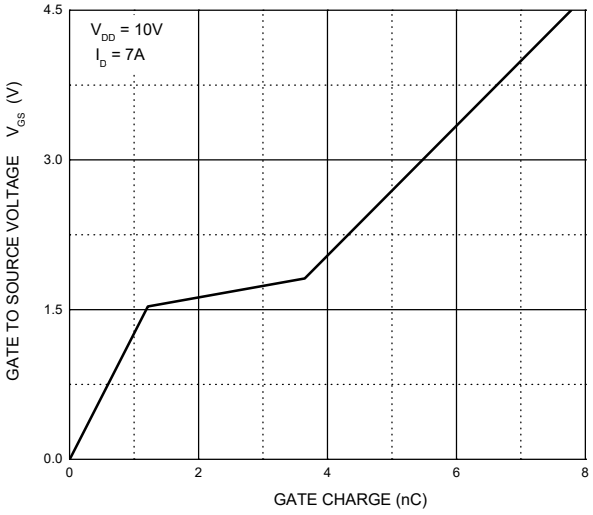


Typical Characteristics

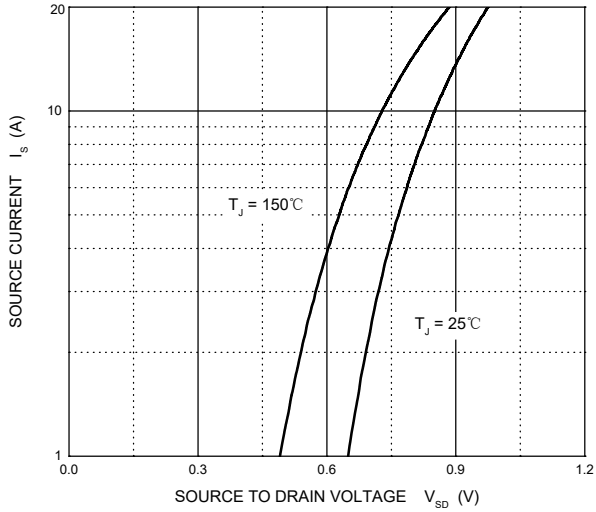
Typical Capacitances



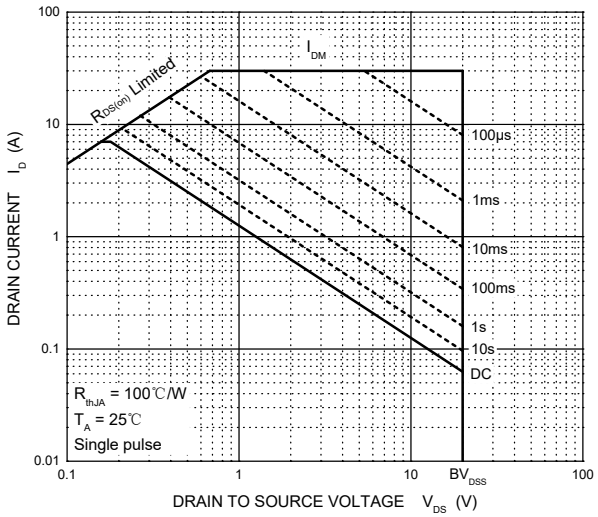
Gate Charge



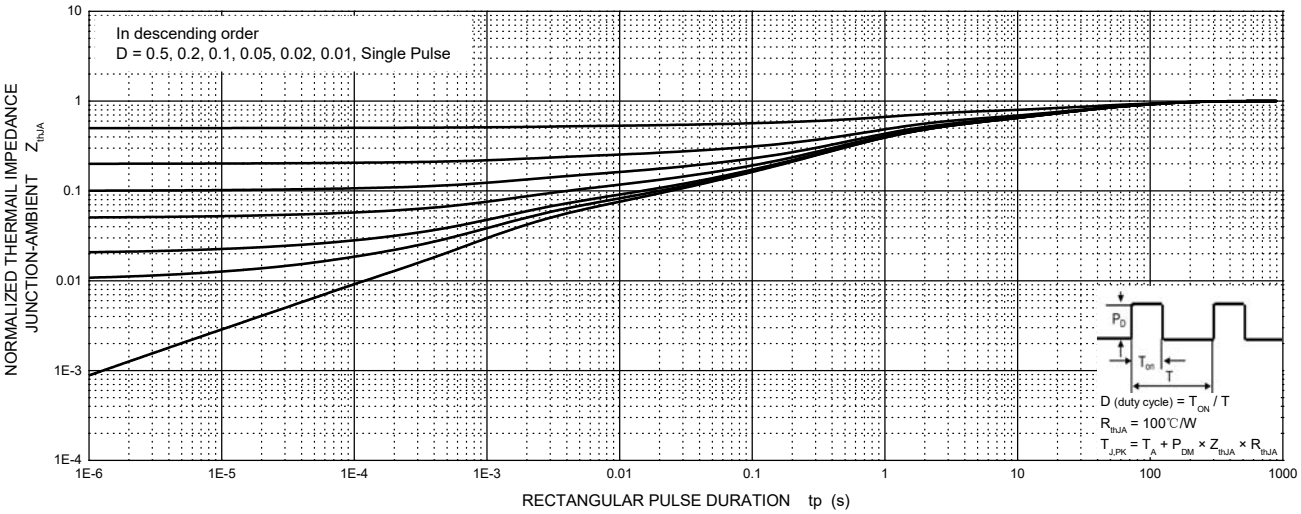
Source-Drain Diode Forward Characteristics



Maximum Safe Operating Area

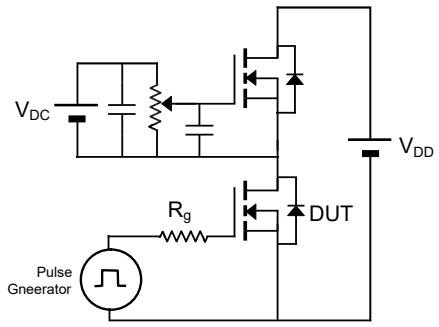


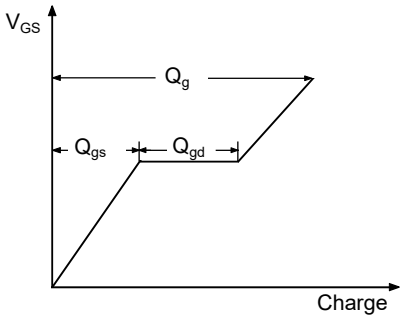
Transient Thermal Impedance, Junction-Case



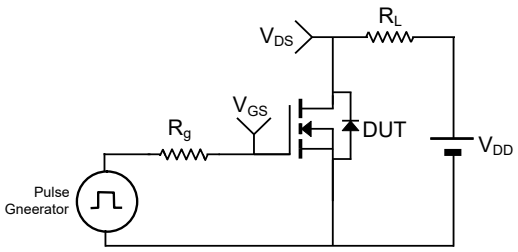
TEST CIRCUIT AND WAVEFOMRS

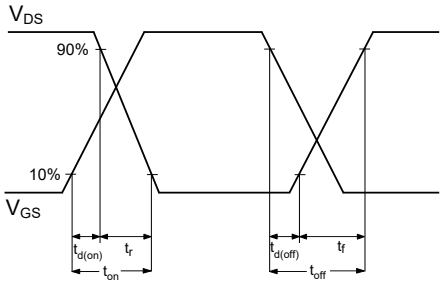
Gate Charge



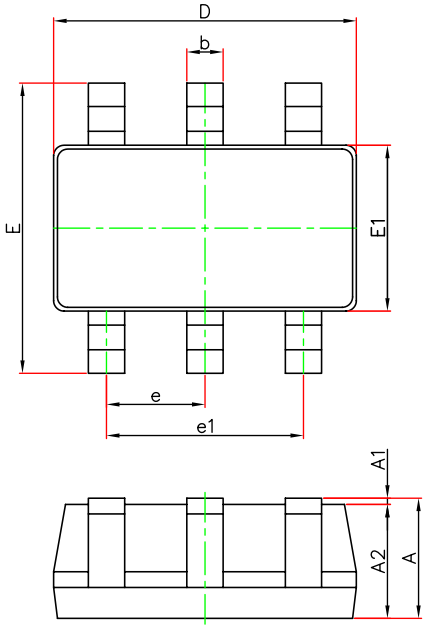


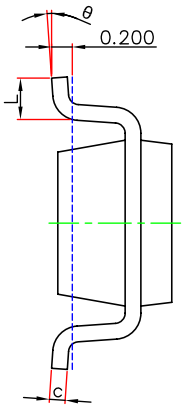
Resistive Load Switching Time





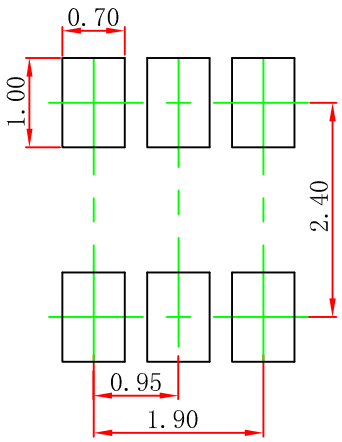
SOT-23-6L Package Outline Dimensions





Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOT-23-6L Suggested Pad Layout



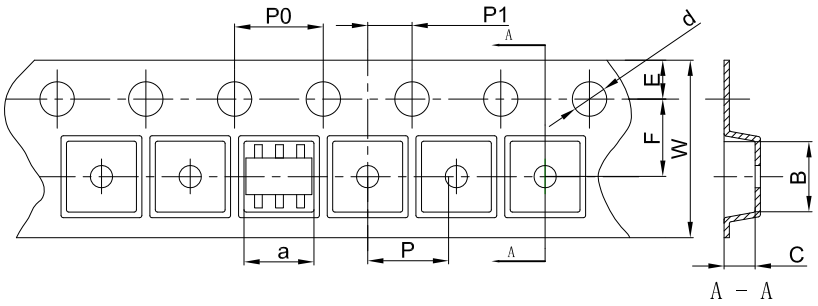
Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

NOTICE

SZCJ reserves the right to make modifications,enhan nts,improvements,corrections or other es without further notice to any product herein. SZCJ does not assume any liability arising out of the application or use of any product described h

SOT-23-6L Tape and Reel

SOT-23-6L Embossed Carrier Tape

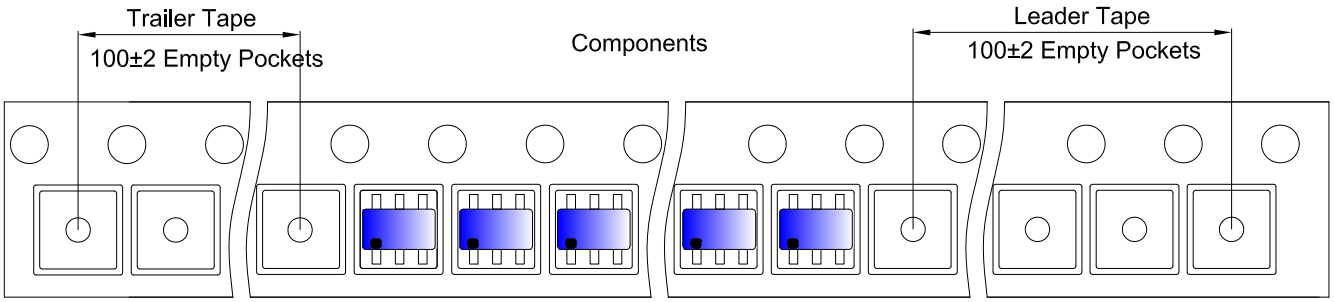


Packaging Description:

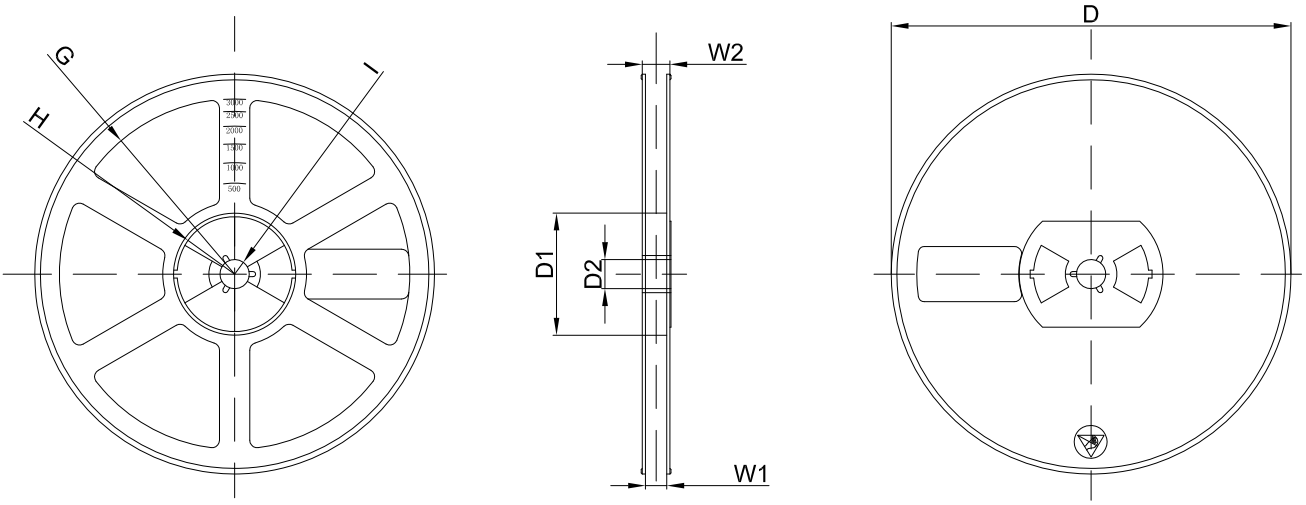
SOT-23-6L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 18.0cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOT-23-6L	3.23	3.17	1.37	Ø1.55	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23-6L Tape Leader and Trailer



SOT-23-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	